

General Description

The MAX4950A dual PCI Express[®] (PCIe) equalizer/ redriver operates from a single +3.3V supply. This device improves signal integrity at the receiver through programmable input equalization and redrive circuitry with output deemphasis to correct for high-frequency losses. This device permits optimal placement of key PCIe components and longer runs of stripline, microstrip, or cable.

The MAX4950A contains two identical channels capable of equalizing PCIe Gen I (2.5GT/s) and Gen II (5.0GT/s) signals. The MAX4950A features electrical idle and receiver detection on each channel and a power-saving mode.

The MAX4950A is available in a small 36-pin (6.0mm x 6.0mm) TQFN package with flowthrough traces for optimal layout and minimal space requirements. The MAX4950A is specified over the 0°C to +70°C commercial operating temperature range.

Applications

Servers

- Industrial PCs
- Test Equipment

Computers

- External Graphics Applications
- Communications Switchers
- Storage Area Networks

_Features

- Single +3.3V Supply Operation
- ◆ PCle Gen I (2.5GT/s) and Gen II (5.0GT/s) Capable Excellent Differential Return Loss:
 ≥ 8dB (f = 1.25GHz to 2.5GHz)
- Very Low Latency with 280ps (typ) Propagation Delay
- Individual Lane Detection
- Three-Level Programmable Input Equalization
- ◆ Three-Level Programmable Output Deemphasis
- Standard, -2.5dB Programmable Output Levels
- On-Chip 50Ω Input/Output Terminations
- Space-Saving, 6.0mm x 6.0mm TQFN Package

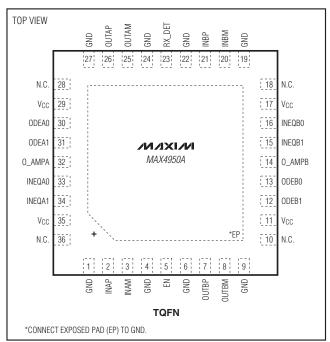
_Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	
MAX4950ACTX+T	0°C to +70°C	36 TQFN-EP*	

+Denotes a lead(Pb)-free/RoHS-compliant package. *EP = Exposed pad.

T = Tape and reel.





PCI Express is a registered trademark of PCI-SIG Corp.

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For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

(Voltages referenced to GND.)

V _{CC} 0.3V to +4.0V
All Other Pins (Note 1)0.3V to $(V_{CC} + 0.3V)$
Continuous Current IN_P, IN_M, OUT_P, OUT_M±30mA
Peak Current IN_P, IN_M, OUT_P, OUT_M
(pulsed for 1µs, 1% duty cycle)±100mA
Continuous Power Dissipation ($T_A = +70^{\circ}C$)
36-Pin TQFN (derate 35.7mW/°C above +70°C)2857mW

Junction-to-Case Thermal Resistance (θ_{JC}	, , ,
36-Pin TQFN	1°C/W
Junction-to-Ambient Thermal Resistance (θ _{JA}) (Note 2)
36-Pin TQFN	28°C/W
Operating Temperature Range	0°C to +70°C
Junction Temperature Range	40°C to +150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: All I/O pins are clamped by internal diodes.

Note 2: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a fourlayer board. For detailed information on package thermal considerations, refer to <u>www.maxim-ic.com/thermal-tutorial</u>.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +3.0V \text{ to } +3.6V, C_{CL} = 75$ nF coupling capacitor on each output, $R_L = 50\Omega$ resistor on each output, $T_A = 0^{\circ}$ C to $+70^{\circ}$ C, unless otherwise noted. Typical values are at V_{CC} = +3.3V and $T_A = +25^{\circ}$ C.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
DC PERFORMANCE						
Power-Supply Range	Vcc		3.0		3.6	V
Supply Current	ICC	$EN = V_{CC}, V_{O_AMPA} = V_{GND}, \\ V_{O_AMPB} = V_{GND} (Note 4)$		130	165	mA
Differential Input Impedance	ZRX-DIFF-DC	DC	80	100	120	Ω
Differential Output Impedance	ZTX-DIFF-DC	DC	80	100	120	Ω
Common-Mode Resistance to GND	Z _{RX-HIGH-} IMP-DC-POS	$V_{IN_P} = V_{IN_M} = 0$ to +200mV, input terminations not powered	50			kΩ
Common-Mode Resistance to GND	Zrx-high- IMP-DC-NEG	$V_{IN_P} = V_{IN_M} = -150$ mV to 0, input terminations not powered				kΩ
Common-Mode Resistance to GND, Input Terminations Powered	Z _{RX-DC}		40	50	60	Ω
Output Short-Circuit Current	ITX-SHORT	Single-ended			90	mA
Common-Mode Delta Between VTX-CM-DC- Active and Idle States ACTIVE- IDLE-DELTA VO_AMP_ = VGND		VO_AMP_ = VGND			100	mV
DC Output Offset During Active State	Active VTX-CM-DC- LINE-DELTA IVOUT_P - VOUT_MI		25	mV		
DC Output Offset During Electrical Idle	VTX-IDLE- DIFF-DC	IVout_p - Vout_ml			10	mV
AC PERFORMANCE						
Differential Input Return Loss	DIAVAGE	f = 0.05GHz to 1.25GHz	10			dB
(Note 5)	RL _{RX-DIFF}	f = 1.25GHz to 2.5GHz	8			ub
Common-Mode Input Return Loss (Note 5)	RL _{RX-CM}	f = 0.05GHz to 2.5GHz	6			dB

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +3.0V \text{ to } +3.6V, C_{CL} = 75$ nF coupling capacitor on each output, $R_L = 50\Omega$ resistor on each output, $T_A = 0^{\circ}$ C to $+70^{\circ}$ C, unless otherwise noted. Typical values are at $V_{CC} = +3.3V$ and $T_A = +25^{\circ}$ C.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
Differential Output Return Loss		f = 0.05GHz to 1.25GHz	10			-10	
(Note 5)	RLTX-DIFF	f = 1.25GHz to 2.5GHz	8			- dB	
Common-Mode Output Return Loss (Note 5)	RL _{TX-CM}	f = 0.05GHz to 2.5GHz	6			dB	
Redriver-Operation Differential Input Signal Range	VRX-DIFF-PP	f = 0.05GHz to 2.5GHz	120		1200	mV _{P-P}	
Full-Swing No-Deemphasis Differential Output Voltage	VTX-DIFF-PP	$ABSIV_{OUT_P} - V_{OUT_M}I; O_AMP_ = GND$	800	1000	1200	mV _{P-P}	
Low-Swing No-Deemphasis Differential Output Voltage	VTX-DIFF- PP-LOW	$ABSIV_{OUT_P} - V_{OUT_M}I; O_AMP_ = V_{CC}$	600	750	900	mV _{P-P}	
Output Deemphasis Ratio, 0dB	V _{TX-DE-} RATIO-0dB	f = 2.5GHz, ODE_1 = GND, ODE_0 = GND, Figure 1 (see Table 3)		0		dB	
Output Deemphasis Ratio, 3.5dB	VTX-DE- RATIO-3.5dB	f = 2.5GHz, ODE_1 = GND, ODE_0 = V _{CC} , Figure 1 (see Table 3)		3.5		dB	
Output Deemphasis Ratio, 6dB	V _{TX-DE-} RATIO-6dB	f = 2.5GHz, ODE_1 = V_{CC} , ODE_0 = V_{CC} or GND, Figure 1 (see Table 3)		6		dB	
nput Equalization, 0dB (Note 6) VRX-EQ- 0dB		f = 2.5GHz, INEQ_1 = GND, INEQ_0 = GND (see Table 2)	0		dB		
Input Equalization, 3.5dB (Note 6)	VRX-EQ- 3.5dB	f = 2.5GHz, INEQ_1 = GND, INEQ_0 = V_{CC} (see Table 2)	3.5		dB		
Input Equalization, 6dB (Note 6)	V _{RX-EQ-} 6dB	f = 2.5GHz, INEQ_1 = V_{CC} , INEQ_0 = V_{CC} or GND (see Table 2)	6		dB		
Output Common-Mode Voltage	VTX-CM-AC- PP	MAX(Vout_p + Vout_m)/2 - MIN(Vout_p + Vout_m)/2	100		mV _{P-P}		
Propagation Delay (Note 5)	T _{PD}	f = 2.5GHz	160	280	400	ps	
Rise/Fall Time	T _{TX-RISE-} FALL	(Note 7)	30		ps		
Rise/Fall Time Mismatch	T _{TX-RF-} MIISMATCH	(Note 7)			20	ps	
Same-Pair Output Skew (Note 5)	T _{SK}	f = 2.5GHz		10	15	ps	
Lane-to-Lane Output Skew (Note 5)	T _{SKL}	f = 2.5GHz	-50 +50		+50	ps	
Deterministic Jitter (Note 5) T _{TX-DJ-DD}		K28.5± pattern, 5.0GT/s, AC coupled, $R_L = 50\Omega$, effects of deemphasis deembedded			15	psp-p	
Random Jitter	T _{TX-RJ-DD}	DIO.2 pattern	1.4		1.4	ps _{RMS}	
Electrical Idle Entry Delay	T _{TX-IDLE-} SET-TO-IDLE	From input to output 15			ns		
Electrical Idle Exit Delay	TTX-IDLE-TO- DIFF-DATA	From input to output		12		ns	



ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +3.0V \text{ to } +3.6V, C_{CL} = 75$ nF coupling capacitor on each output, $R_L = 50\Omega$ resistor on each output, $T_A = 0^{\circ}$ C to $+70^{\circ}$ C, unless otherwise noted. Typical values are at $V_{CC} = +3.3V$ and $T_A = +25^{\circ}$ C.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Electrical Idle Detect Threshold	VTX-IDLE- THRESH		65	95	120	mV _{P-P}
Output Voltage During Electrical Idle (AC)					25	mV _{P-P}
Receiver Detect Pulse Amplitude (Note 5)	VTX-RCV- DETECT	Voltage change in positive direction			600	mV
Receiver Detect Pulse Width				100		ns
Receiver Detect Retry Period				200		ns
CONTROL LOGIC (INEQ_1, INEQ_	_0, ODE_1, C	DDE_0, EN, RX_DET, O_AMP_)				
Input Logic-Level Low	VIL				0.6	V
Input Logic-Level High	VIH		1.4			V
Input Logic Hysteresis	VHYST			130		mV
Input Leakage Current	lin	VCONTROL_LOGIC = +0.5V or +1.5V	-50		+50	μA

Note 3: All devices are 100% production tested at $T_A = +70^{\circ}C$. Specifications for all temperature limits are guaranteed by design.

Note 4: Currents are applicable for both PCIe Generation I and Generation II speeds. Table 5 summarizes the predicted power consumption.

Note 5: Guaranteed by design, unless otherwise noted.

Note 6: Equivalent to the same amount of deemphasis driving the output.

Note 7: Rise and fall times are measured using 20% and 80% levels.

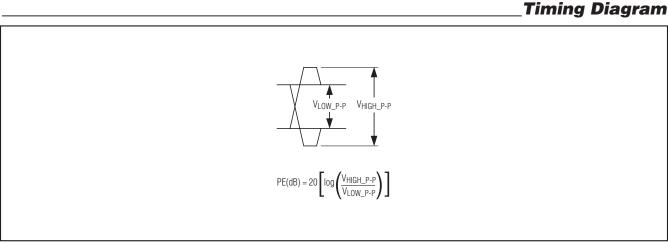
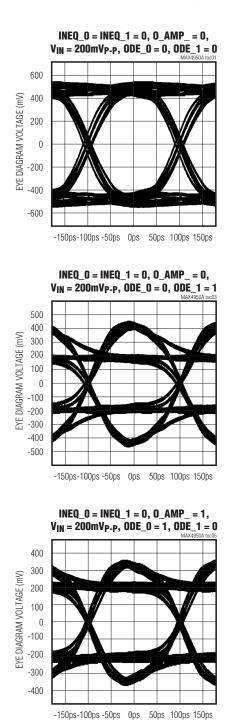


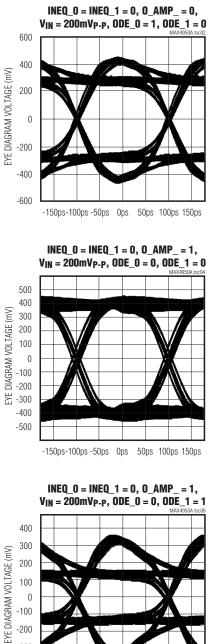
Figure 1. Illustration of Output Deemphasis

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 $(V_{CC} = +3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$

Typical Operating Characteristics



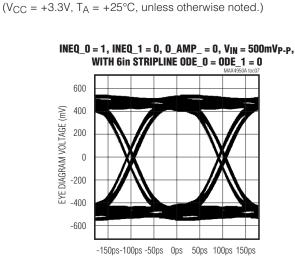
-200 -300 -400

-150ps-100ps -50ps 0ps 50ps 100ps 150ps

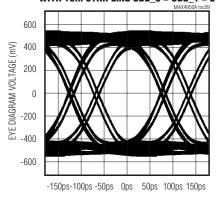
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Typical Operating Characteristics (continued)

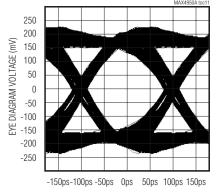


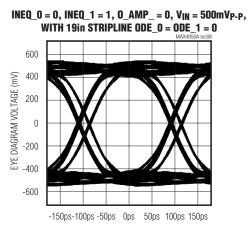


$$\label{eq:INEQ_0} \begin{split} \text{INEQ_0} &= \text{INEQ_1} = 0, \ \text{O}_{\text{AMP}} = 0, \ \text{V}_{\text{IN}} = 500 \text{mV}_{\text{P-P}}, \\ \text{WITH 19in STRIPLINE ODE_0} &= \text{ODE_1} = 0 \end{split}$$

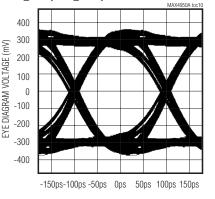




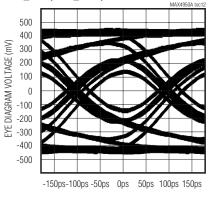




INEQ_0 = INEQ_1 = 0, 0_AMP_ = 1, V_{IN} = 200mV_{P-P}, ODE_0 = 1, ODE_1 = 0, OUTPUT AFTER 6in STRIPLINE



 $INEQ_0 = INEQ_1 = 0$, $0_AMP_ = 0$, $V_{IN} = 200mV_{P-P}$, $ODE_0 = 0$, $ODE_1 = 0$, OUTPUT AFTER 19in STRIPLINE



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Pin Description

PIN	NAME	FUNCTION
1, 4, 6, 9, 19, 22, 24, 27	GND	Ground
2	INAP	Noninverting Input A
3	INAM	Inverting Input A
5	EN	Enable Input. Drive EN low for standby mode. Drive EN high for normal mode. EN is internally pulled down by a $50k\Omega$ (typ) resistor.
7	OUTBP	Noninverting Output B
8	OUTBM	Inverting Output B
10, 18, 28, 36	N.C.	No Connection. Not internally connected.
11, 17, 29, 35	V _{CC}	Power-Supply Input. Bypass V_{CC} to GND with $1\mu F$ and $0.01\mu F$ capacitors in parallel as close as possible to the device.
12	ODEB1	Output B Deemphasis Control MSB. ODEB1 is internally pulled down by a $50k\Omega$ (typ) resistor. See Table 3.
13	ODEB0	Output B Deemphasis Control LSB. ODEB0 is internally pulled down by a $50k\Omega$ (typ) resistor. See Table 3.
14	O_AMPB	Output B Amplitude Selection Input. O_AMPB is internally pulled down by a $50k\Omega$ (typ) resistor.
15	INEQB1	Input B Equalization Control MSB. INEQB1 is internally pulled down by a 50k Ω (typ) resistor. See Table 2.
16	INEQB0	Input B Equalization Control LSB. INEQB0 is internally pulled down by a 50k Ω (typ) resistor. See Table 2.
20	INBM	Inverting Input B
21	INBP	Noninverting Input B
23	RX_DET	Receiver-Detection Control Bit. Toggle RX_DET to initiate receiver detection. RX_DET is internally pulled down by a $50k\Omega$ (typ) resistor.
25	OUTAM	Inverting Output A
26	OUTAP	Noninverting Output A
30	ODEA0	Output A Deemphasis Control LSB. ODEA0 is internally pulled down by a 50k Ω (typ) resistor. See Table 3.
31	ODEA1	Output A Deemphasis Control MSB. ODEA1 is internally pulled down by a 50k Ω (typ) resistor. See Table 3.
32	O_AMPA	Output A Amplitude Selection Input. O_AMPA is internally pulled down by a 50k Ω (typ) resistor.
33	INEQA0	Input A Equalization Control LSB. INEQA0 is internally pulled down by a $50k\Omega$ (typ) resistor. See Table 2.
34	INEQA1	Input A Equalization Control MSB. INEQA1 is internally pulled down by a 50k Ω (typ) resistor. See Table 2.
_	EP	Exposed Pad. Internally connected to GND. Connect EP to a large ground plane to maximize thermal performance. EP is not intended as an electrical connection point.







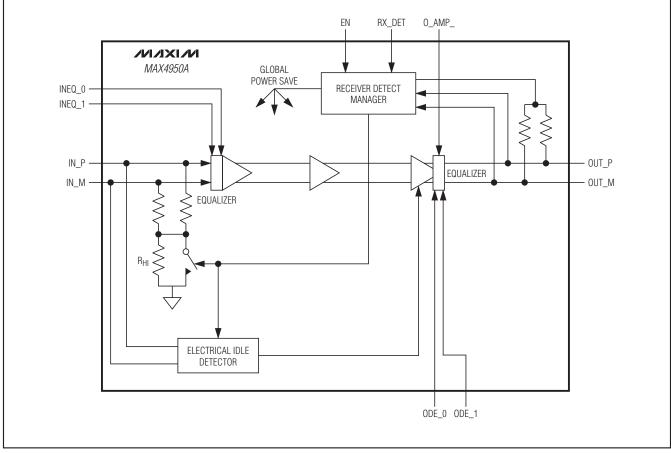


Figure 2. Block Diagram of Each Channel

MAX4950A

Dual PCI Express Equalizer/Redriver

Detailed Description

The MAX4950A dual equalizer/redriver is designed to support both Gen I (2.5GT/s) and Gen II (5.0GT/s) PCIe data rates. The device contains two identical drivers with idle/receive detect on each lane and equalization to compensate for circuit-board loss. Signal integrity at the receiver is improved by the use of programmable input equalization circuitry. The MAX4950A features individual channel output amplitude selection inputs, O_AMPA and O_AMPB (Table 1), and programmable output deemphasis, permitting optimal placement of key PCIe components and longer runs of stripline, microstrip, or cable.

Table 1. Output Amplitude Selection

O_AMPA/ O_AMPB	DIFFERENTIAL OUTPUT VOLTAGE (mV _{P-P})
0	1000 (typ)
1	750 (typ)

Programmable Input Equalization

The MAX4950A features programmable input equalizers capable of providing 0dB, 3.5dB, or 6dB of highfrequency boost on either channel (see Table 2).

Table 2. Input Equalization

INEQ_1	INEQ_0	INPUT EQUALIZATION (dB)
0	0	0
0	1	3.5 (typ)
1	Х	6 (typ)

X = Don't care.

Programmable Output Deemphasis

The MAX4950A features programmable output deemphasis on either channel by setting two control bits, ODE_1 and ODE_0, for deemphasis ratios of 0dB, 3.5dB, and 6dB (see Table 3).

Table 3. Output Deemphasis

ODE_1	ODE_0	OUTPUT DEEMPHASIS RATIO (dB)
0	0	0
0	1	3.5 (typ)
1	Х	6 (typ)

X = Don't care.



Receiver Detection

The MAX4950A features receiver detection on each channel. Upon initial power-up, if EN is high, receiver detection initializes. Receiver detection can also be initiated on a rising or falling edge of the RX_DET input when EN is high. During this time, the part remains in low-power standby mode and the outputs are squelched, despite the logic-high state of EN. Once started, receiver detection repeats indefinitely on each channel. Once a receiver is detected on one of the channels, up to three more attempts are made on the other channel. Upon receiver detection, channel output and electrical idle detection are enabled (see Table 4).

Table 4. Receiver-Detection InputFunction

RX_DET	EN	DESCRIPTION		
Х	0	Receiver detection inactive		
0	1	Following a rising or falling edge, indefinite retry until receiver detected		
Rising or Falling Edge	1	Initiate receiver detection		
1	1 Following a rising or falling ec indefinite retry until receiver det			

X = Don't care.

Electrical Idle Detection

The MAX4950A features electrical idle detection to prevent unwanted noise from being redriven at the output. If the MAX4950A detects that the differential input has fallen below VTX-IDLE-THRESH, the MAX4950A squelches the output. For differential input signals that are above VTX-IDLE-THRESH, the MAX4950A turns on the output and redrives the signal.

Power-Saving Features

The MAX4950A features an enable input (EN) to shut down the device and reduce supply current. To place the device in shutdown mode, drive EN low. To enable the device, drive EN high. During normal operation, supply current can also be reduced by reducing the channel output amplitudes. Table 5 shows typical power consumption differences between shutdown mode and normal operation with different output redrive strengths.

			-	-	-	
EN	O_AMPB	O_AMPA	QUIESCENT POWER SUPPLY CURRENT (typ) (mA)	QUIESCENT POWER SUPPLY CURRENT (max) (mA)	QUIESCENT POWER DISSIPATION (3.3V, typ) (mW)	QUIESCENT POWER DISSIPATION (3.6V, max) (mW)
0	0	0	60	75	198	270
0	0	1	55	68	182	243
0	1	0	55	68	182	243
0	1	1	50	60	165	216
1	0	0	130	165	429	594
1	0	1	125	157	413	565
1	1	0	125	157	413	565
1	1	1	120	150	396	540

Table 5. Quiescent Power Dissipation with Equalization and Deemphasis

_Applications Information

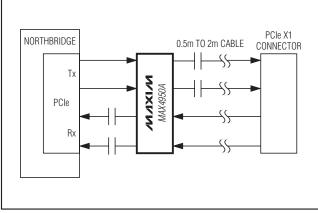


Figure 3. Typical Application Circuit—MAX4950A Used as X1 Lane Cable Driver

Layout

Circuit-board layout and design can significantly affect the performance of the MAX4950A. Use good high-frequency design techniques, including minimizing ground inductance and using controlled-impedance transmission lines on data signals. It is recommended to run receive and transmit on different layers to minimize crosstalk and to place power-supply decoupling capacitors as close as possible to V_{CC}. Always connect V_{CC} to a power plane.

Exposed Pad Package

The exposed-pad, 36-pin, TQFN package incorporates features that provide a very low thermal resistance path for heat removal from the IC. The exposed pad on the MAX4950A must be soldered to the circuit-board ground plane for proper thermal performance. For more information on exposed-pad packages, refer to Maxim Application Note HFAN-08.1: *Thermal Considerations of QFN and Other Exposed-Paddle Packages.*

Power-Supply Sequencing

Caution: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the device.

Proper power-supply sequencing is recommended for all devices. Always apply GND then V_{CC} before applying signals, especially if the signal is not current limited.

Chip Information

PROCESS: BiCMOS

Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
36 TQFN	T3666+2	<u>21-0141</u>

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MAX4950A

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